TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

2SC2712

Audio Frequency General Purpose Amplifier Applications

• High voltage and high current: VCEO = 50 V, IC = 150 mA (max)

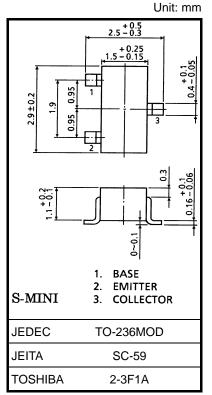
• Excellent hFE linearity: hFE (IC = 0.1 mA) / hFE (IC = 2 mA)

= 0.95 (typ.)

- High hFE: hFE = 70~700
- Low noise: NF = 1dB (typ.), 10dB (max)
- Complementary to 2SA1162
- Small package

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V _{CBO}	60	V	
Collector-emitter voltage	V _{CEO}	50	V	
Emitter-base voltage	V _{EBO}	5	V	
Collector current	Ι _C	150	mA	
Base current	Ι _Β	30	mA	
Collector power dissipation	PC	150	mW	
Junction temperature	Тj	125	°C	
Storage temperature range	T _{stg}	-55~125	°C	

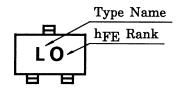


Weight: 0.012 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Marking



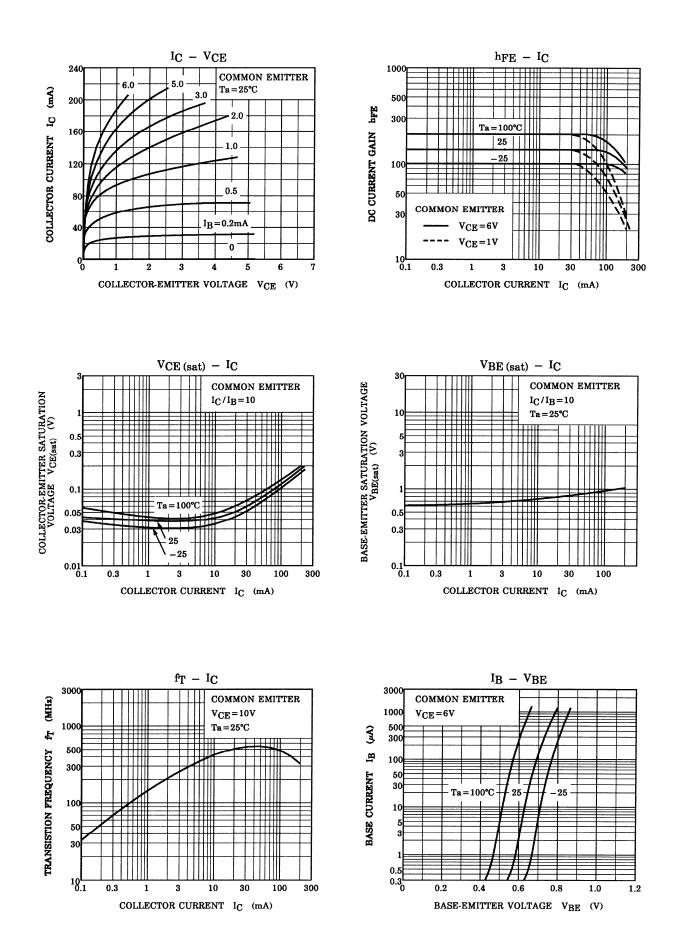
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 60 V, I_E = 0$	_		0.1	μΑ
Emitter cut-off current	I _{EBO}	$V_{EB} = 5 V, I_{C} = 0$	_	_	0.1	μΑ
DC current gain	h _{FE} (Note)	$V_{CE} = 6 \text{ V}, \text{ I}_{C} = 2 \text{ mA}$	70	_	700	
Collector-emitter saturation voltage	V _{CE (sat)}	$I_{C} = 100 \text{ mA}, I_{B} = 10 \text{ mA}$	_	0.1	0.25	V
Transition frequency	f _T	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	80	_	_	MHz
Collector output capacitance	C _{ob}	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1 \text{ MHz}$	_	2.0	3.5	pF
Noise figure	NF	V_{CE} = 6 V, I_C = 0.1 mA, f = 1 kHz, R_g = 10 $k\Omega$		1.0	10	dB

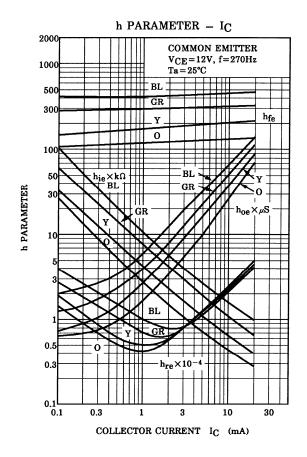
Note: hFE classification O (O): 70~140, Y (Y): 120~240, GR (G): 200~400, BL (L): 350~700

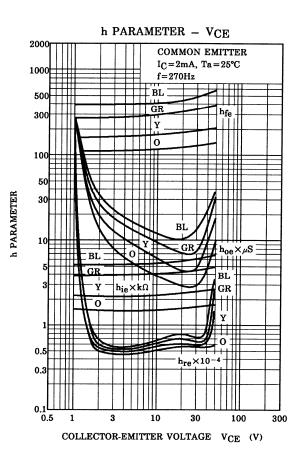
() marking symbol

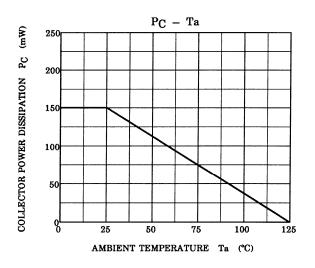
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